

# RV1S2281A

OPERATING AMBIENT TEMPERATURE 115°C, 4-PIN SSOP WITH 8.2mm CREEPAGE DISTANCE (LSSOP) PHOTOCOUPLER

## DESCRIPTION

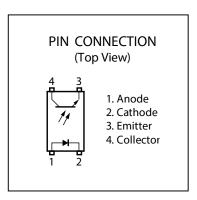
The RV1S2281A is an optically coupled isolator containing a GaAs light emitting diode and an NPN silicon phototransistor.

This package is very small and thin with long creepage distance(8.2mm).

This small product is suitable for various interface circuits which require surface mounting and high-density mounting.

#### FEATURES

- Small and long creepage (8.2 mm, LSSOP)
- Operating ambient temperature: 115°C
- High isolation voltage (BV = 5000 Vr.m.s.)
- Embossed tape product : RV1S2281ACCSP-10Yx#KC0 : 3500 pcs/reel
- Pb-Free product
- Safety standard
  - UL : UL1577, Double protection
  - CSA : CAN/CSA-C22.2 No.62368-1, Reinforced insulation
  - VDE : DIN EN 60747-5-5 (Option)



#### APPLICATIONS

- Robot controller
- Industrial inverter
- AC Servo
- Programmable logic controller
- Measurement equipment
- Power supply

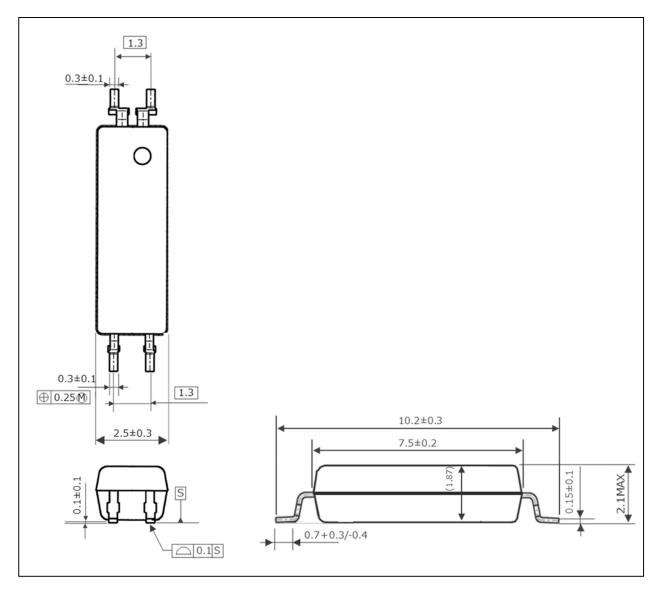
R08DS0185EJ0100

Rev.1.00

Nov 11,2019



## PACKAGE DIMENSIONS (UNIT : mm)



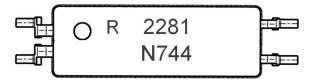
Weight: 0.075g (Typ.)

## PHOTOCOUPLER CONSTRUCTIONS

Parameter	UNIT (MIN.)
Air Distance	8.2 mm
Creepage Distance	8.2 mm
Isolation Distance	0.15 mm



## MARKING EXAMPLE



F	ર	An initial of "Renesas"	
2281		Product Part Number *	
(	)		No.1 pin Mark
N744	N	Rank Code	
	744	Assembly Lot	
		7 Last one-digit of Assembly Year	
		44 Weekly Serial Code	

\* ) Applicable type numbers listed below RV1S 2281 ACCSP-10Yx

Marking type number. " RV1S" and "ACCSP-10Yx" " are omitted from original type number

#### ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification <sup>*1</sup>	Packing Style	Safety Standard Approval	Application Part Number <sup>*2</sup>
RV1S2281ACCSP -10YC	RV1S2281ACCSP -10YC#SC0 RV1S2281ACCSP -10YC#KC0	Pb-Free and Halogen Free (Ni/Pd/Au)	20 pcs(Tape 20 pcs cut) Embossed Tape 3500 pcs/reel	Standard products (UL, CSA approved)	RV1S2281A
RV1S2281ACCSP -10YV	RV1S2281ACCSP -10YV#SC0		20 pcs(Tape 20 pcs cut)	UL, CSA, DIN EN 60747-5-5	
	RV1S2281ACCSP -10YV#KC0		Embossed Tape 3500 pcs/reel	approved	

Notes:\*1. When specifying CTR rank, please add "/CTR rank" after Order Number.

ex. L rank : RV1S2281ACCSP-10YC#SC0/L

Notes:\*2. For the application of the Safety Standard, following part number should be used.



## ABSOLUTE MAXIMUM RATINGS (TA=25°C, unless otherwise specified)

	Parameter	Symbol	Ratings	Unit
Diode	Forward Current (DC)	lF	30	mA
	Reverse Voltage	VR	6	V
	Power Dissipation Derating*1	⊿P <sub>D</sub> /°C	0.6	mW/°C
	Power Dissipation	PD	60	mW
	Peak Forward Current*2	I <sub>FP</sub>	0.5	А
Transistor	Collector to Emitter Voltage	VCEO	80	V
	Emitter to Collector Voltage	VECO	5	V
	Collector Current	lc	30	mA
	Power Dissipation Derating*1	⊿Pc/°C	1.2	mW/°C
	Power Dissipation	Pc	120	mW
Isolation Vo	bltage <sup>*3</sup>	BV	5000	Vr.m.s.
Operating A	Operating Ambient Temperature		-40 ~ +115	°C
Storage Te	Storage Temperature		-40 ~ +125	°C

**\*1** Derating from  $T_A = 25^{\circ}C$ 

\***2** PW = 100 μs, Duty Cycle = 1%

\*3 AC voltage for 1 minute at  $T_A = 25^{\circ}$ C, RH = 60% between input and output. Pins 1-2 shorted together, 3-4 shorted together.

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^{\circ}C$ )

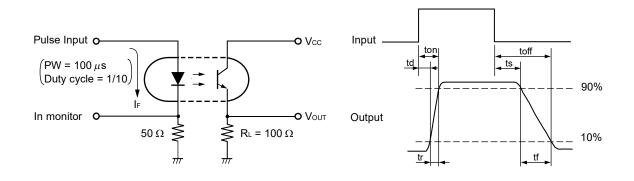
	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	I <sub>F</sub> = 5 mA		1.15	1.4	V
	Reverse Current	I <sub>R</sub>	V <sub>R</sub> = 5 V			5	μA
	Terminal Capacitance	Ct	V = 0 V, f = 1 MHz		10		pF
Transistor	Collector to Emitter Dark Current	ICEO	I <sub>F</sub> =0mA, V <sub>CE</sub> =80V			100	nA
Coupled	Current Transfer Ratio	CTR	I <sub>F</sub> = 5 mA, V <sub>CE</sub> = 5 V	50	200	400	%
	(Ic/I⊧)* <b>1</b>		I <sub>F</sub> = 1 mA, V <sub>CE</sub> = 5 V	10	50		
	Collector Saturation Voltage	VCE (sat)	I <sub>F</sub> = 10 mA, I <sub>C</sub> = 2 mA			0.3	V
	Isolation Resistance	R <sub>I-0</sub>	V <sub>I-O</sub> = 1kV <sub>DC</sub>	10 <sup>11</sup>			Ω
	Isolation Capacitance	C <sub>I-O</sub>	V = 0 V, f = 1 MHz		0.4		pF
	Rise Time*2	tr	$V_{CC} = 5 V, I_C = 2 mA$		4		μS
	Fall Time <sup>*2</sup>	t <sub>f</sub>	R <sub>L</sub> = 100 Ω		5		

#### \*1. CTR rank

CTR rank	CTR(%)	Condition
N	50 ~ 400	$I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$
	10 ~	I <sub>F</sub> = 1 mA, V <sub>CE</sub> = 5 V
М	50~150	$I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$
	10 ~	$I_F = 1 \text{ mA}, V_{CE} = 5 \text{ V}$
L	100~300	$I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$
	20 ~	$I_F = 1 \text{ mA}, V_{CE} = 5 \text{ V}$
W	130~260	$I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$
	20 ~	$I_F = 1 \text{ mA}, V_{CE} = 5 \text{ V}$

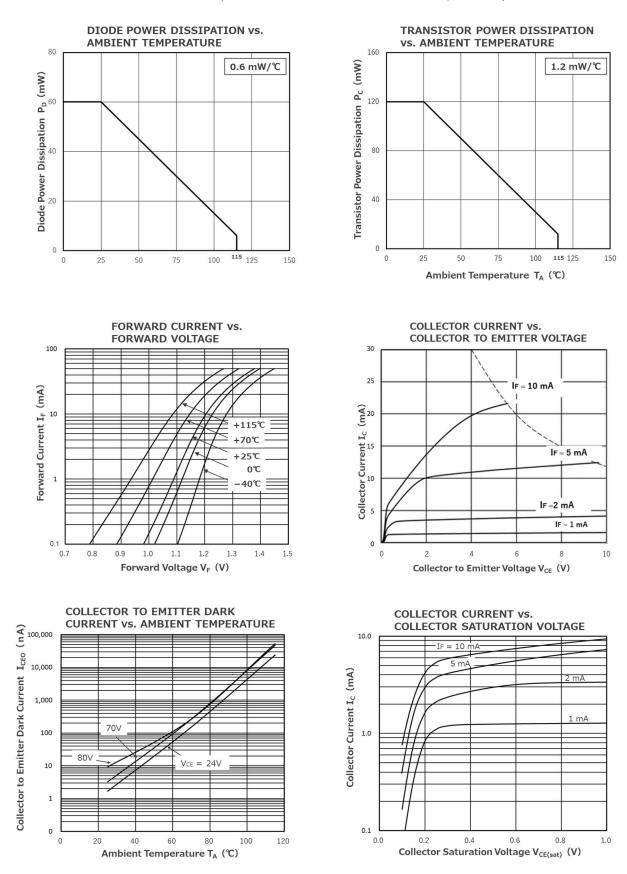


\*2. Test circuit for switching time





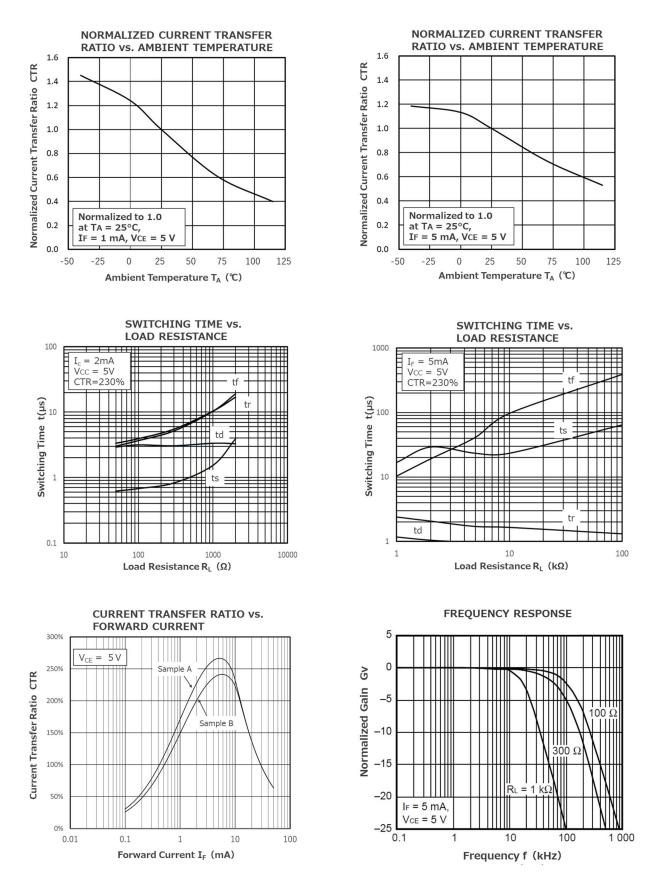
## TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)



Remark The graphs indicate nominal characteristics.



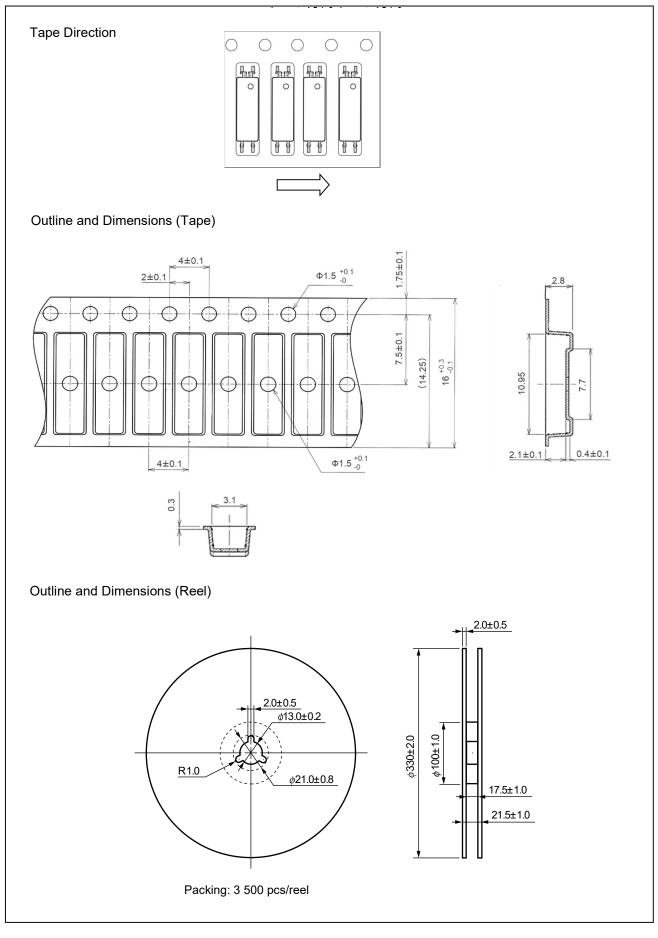
## TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)



Remark The graphs indicate nominal characteristics.

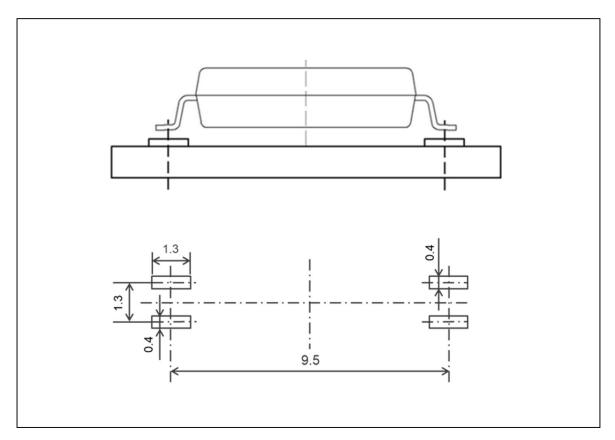


## TAPING SPECIFICATIONS (UNIT: mm)





## RECOMMENDED MOUNT PAD DIMENSIONS (UNIT : mm)



Remark All dimensions in this figure must be evaluated before use.



## NOTES ON HANDLING

- 1. Recommended soldering conditions
  - (1) Infrared reflow soldering
    - Peak reflow temperature
    - Time of peak reflow temperature
    - Time of temperature higher than 220°C •
    - Time to preheat temperature from 120 to 180°C
    - Number of reflows
    - Flux

260°C or below (package surface temperature) 10 seconds or less

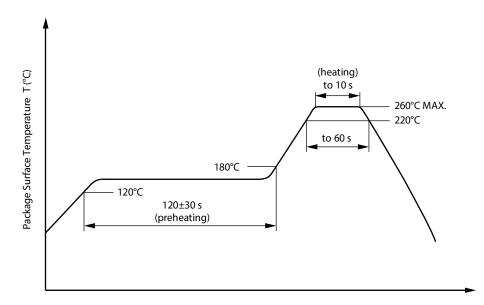
60 seconds or less

120±30 s

- - Three

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

#### **Recommended Temperature Profile of Infrared Reflow**



#### (2) Wave soldering

Time (s)

- Temperature 260°C or below (molten solder temperature)
- Time 10 seconds or less
- Preheating conditions 120°C or below (package surface temperature)
- Number of times One (Allowed to be dipped in solder including plastic mold portion.)
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

#### (3) Soldering by Soldering Iron

Time (each pins)

- Peak Temperature (lead part temperature) 350°C or below
  - 3 seconds or less
- Flux Rosin flux containing small amount of chlorine
  - (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)
- (a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead
- (b) Please be sure that the temperature of the package would not be heated over 100°C

#### (4) Cautions

- Flux Cleaning
  - Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.
- Do not use fixing agents or coatings containing halogen-based substances.

#### 2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collectoremitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.



3. Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler

Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

#### USAGE CAUTIONS

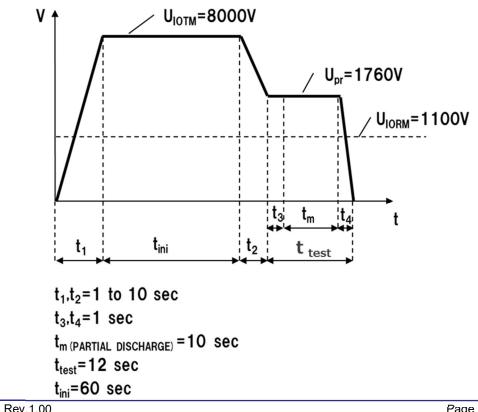
- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.



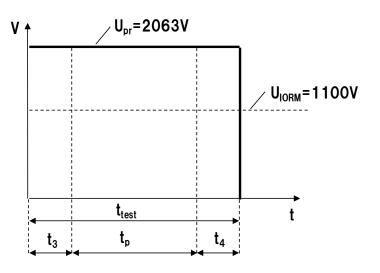
#### SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

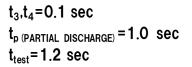
Parameter	Symbol	Rating	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		40/115/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $U_{pr} = 1.6 \times U_{IORM}, P_d < 5 pC$	Uiorm Upr	1 100 1 760	V <sub>peak</sub> V <sub>peak</sub>
Test voltage (partial discharge test, procedure b for all devices) $U_{pr}$ = 1.875 × U <sub>IORM</sub> , Pd < 5 pC	Upr	2 063	$V_{peak}$
Highest permissible overvoltage	UIOTM	8 000	V <sub>peak</sub>
Degree of pollution (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303-11))	СТІ	400	
Material group (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))		П	
Storage temperature range	T <sub>stg</sub>	$-40 \sim +125$	°C
Operating temperature range	T <sub>A</sub>	$-40 \sim +115$	°C
Isolation resistance, minimum value $V_{IO} = 500 \text{ V dc at } T_A = 25^{\circ}\text{C}$ $V_{IO} = 500 \text{ V dc at } T_A \text{ MAX. at least } 100^{\circ}\text{C}$	Ris MIN. Ris MIN.	10 <sup>12</sup> 10 <sup>11</sup>	Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature	Tsi	175	°C
Current (input current $I_F$ , Psi = 0) Power (output or total power dissipation) Isolation resistance $V_{IO}$ = 500 V dc at $T_A$ = Tsi	lsi Psi Ris MIN.	400 700 10 <sup>9</sup>	mA mW Ω

## Method a) Destructive Test, Type and Sample Test



Method b) Non-destructive Test, 100% Production Test







Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.
	• Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
	<ol> <li>Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.</li> </ol>
	2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
	Do not burn, destroy, cut, crush, or chemically dissolve the product.
	• Do not lick the product or in any way allow it to enter the mouth.

All trademarks and registered trademarks are the property of their respective owners.



#### Notice



Renesas Electronics Malaysia Sdn.Bhd. Unit No 3A-1 Level 3A Tower 8 UOA Business Park, No 1 Jalan Pengaturcara U1/51A, Seksyen U1, 40150 Shah Alam, Selangor, Malaysia Tel: +60-3-5022-1288, Fax: +60-3-5022-1290

Renesas Electronics India Pvt. Ltd. No.777C, 100 Feet Road, HAL 2nd Stage, Indiranagar, Bangalore 560 038, India Tel: +91-80-67208700

Renesas Electronics Korea Co., Ltd. 17F, KAMCO Yangjae Tower, 262, Gangnam-daero, Gangnam-gu, Seoul, 06265 Korea Tel: +82-2-558-3737, Fax: +82-2-558-5338

## **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Transistor Output Optocouplers category:

Click to view products by Renesas manufacturer:

Other Similar products are found below :

LTV-814S-TA LTV-824HS LTV-852S 66095-001 6N136-X017T MCT6-X007 MOC8101-X017T PS2561A-1-W-A PS2561B-1-L-A PS2561L-1-V-A MRF658 IL755-1X007 ILD74-X001 ILQ615-2X017 ILQ615-3X016 LDA102S LDA110S PS2561-1-V-W-A PS2561AL-1-V-A PS2561L1-1-L-A PS2701A-1-F3-P-A PS2801-1-F3-P-A PS2911-1-L-AX CNY17-2X017 CNY17-4X001 CNY17-4X017 CNY17F-1X007 CNY17F-2X017 CNY17F-4X001 CNY17G-1 LTV-214 LTV-702VB LTV-733S LTV-816S-TA LTV-825S TCET1113 TCET2100 4N25-X007T IL215AT ILD615-1X007 ILQ2-X007 VOS615A-2T WPPC-A11066AA WPPC-A11066AD WPPC-A11084ASS WPPC-A21068AA WPPC-D11066AA WPPC-D21068ED WPPC-D410616EA WPPC-D410616ED